

WEBENCH® Design Report

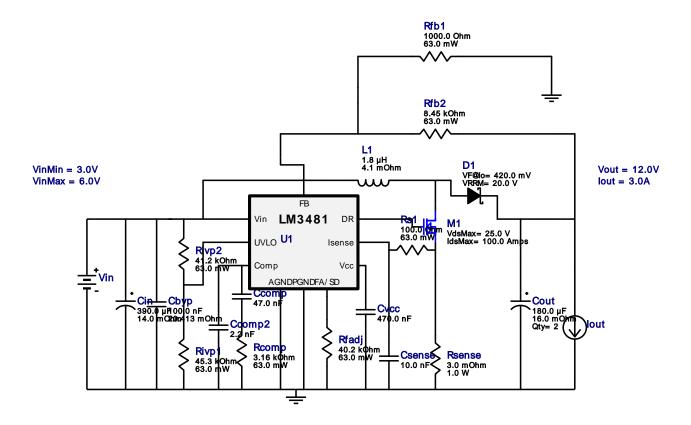
VinMax = 6.0V Vout = 12.0V Iout = 3.0A

VinMin = 3.0V

Topology = Boost Created = 3/15/15 10:03:59 PM BOM Cost = \$5.17 Footprint = 626.0 mm² BOM Count = 20 Total Pd = 3.54W

Device = LM3481MM/NOPB

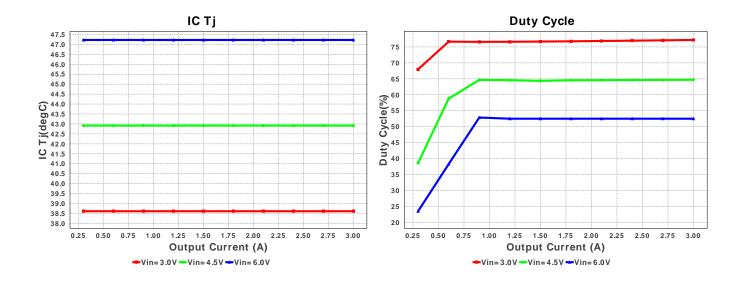
Design: 3789096/1 LM3481MM/NOPB LM3481MM/NOPB 3.0V-6.0V to 12.00V @ 3.0A

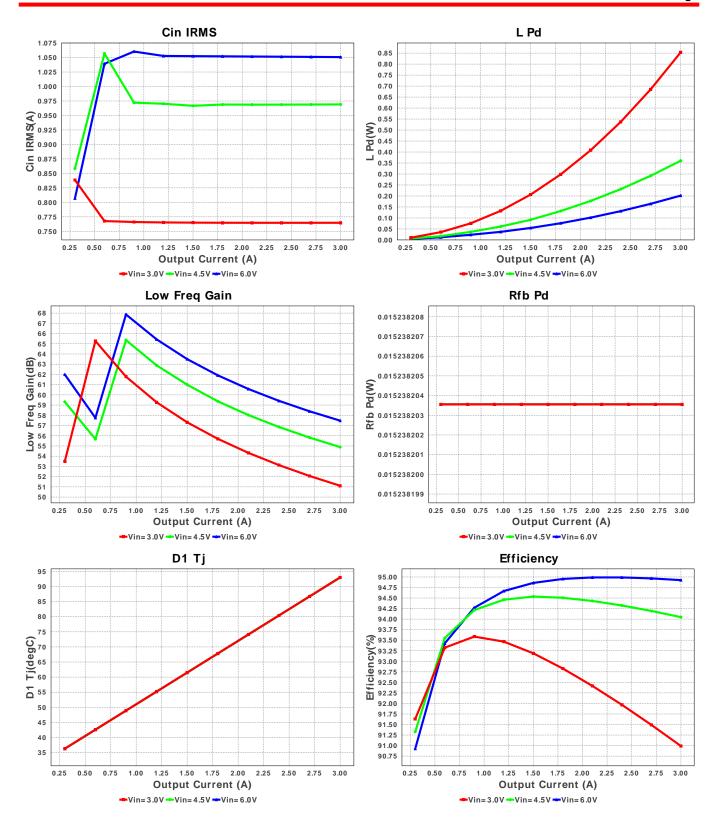


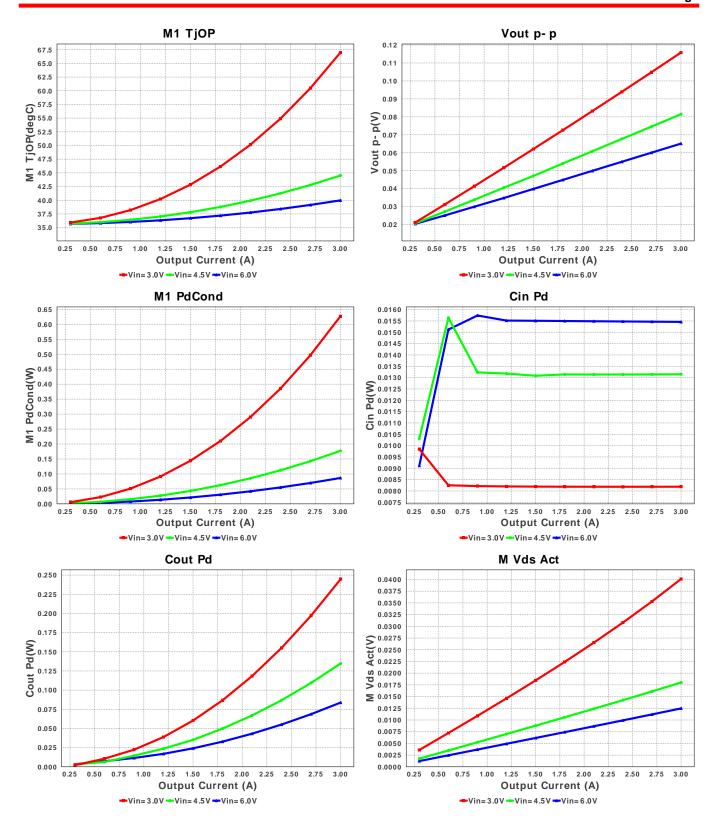
Electrical BOM

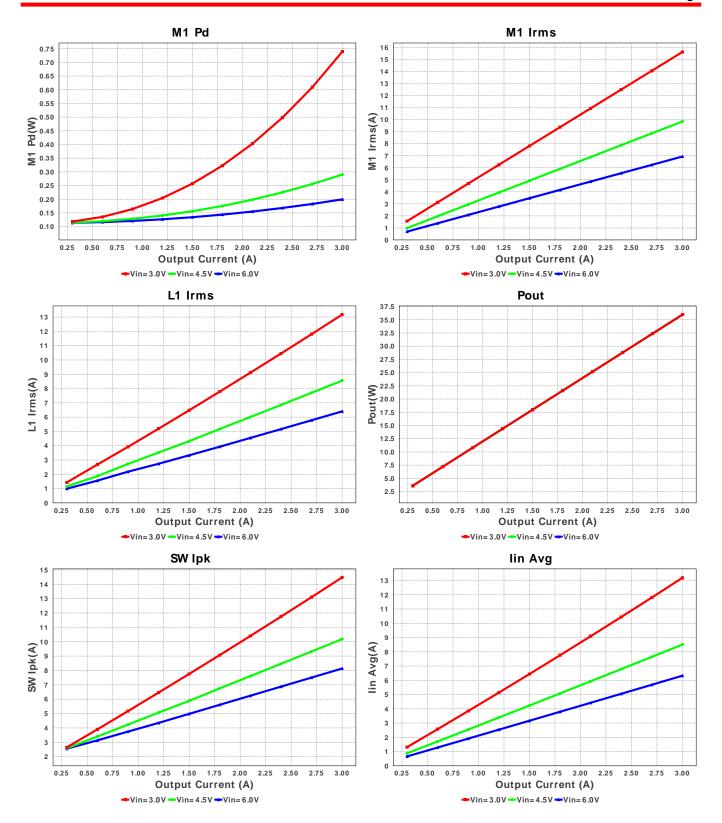
| # | Name | Manufacturer | Part Number | Properties | Qty | Price | Footprint |
|----|--------|---------------|-----------------------------------|--|-----|--------|-----------------------------------|
| 1. | Cbyp | TDK | C1005X5R0J104K Series= X5R | Cap= 100.0 nF ESR= 20.413 mOhm VDC= 6.3 V IRMS= 0.0 A | 1 | \$0.01 | 1005 3 mm ² |
| 2. | Ccomp | Taiyo Yuden | TMK212B7473KD-T Series= X7R | Cap= 47.0 nF VDC= 25.0 V IRMS= 0.0 A | 1 | \$0.01 | 0805 7 mm ² |
| 3. | Ccomp2 | Yageo America | CC0805KRX7R9BB222 Series= X7R | Cap= 2.2 nF VDC= 50.0 V IRMS= 0.0 A | 1 | \$0.01 | 0805 7 mm ² |
| 4. | Cin | Panasonic | 20SVPF390M Series= 1273 | Cap= 390.0 uF ESR= 14.0 mOhm VDC= 20.0 V IRMS= 4.95 A | 1 | \$0.63 | CAPSMT_62_E12 106 mm ² |
| 5. | Cout | Panasonic | 25SVPF180M Series= 1273 | Cap= 180.0 uF ESR= 16.0 mOhm VDC= 25.0 V IRMS= 4.65 A | 2 | \$0.61 | CAPSMT_62_E12 106 mm ² |
| 6. | Csense | MuRata | GRM216R71H103KA01D Series= X7R | Cap= 10.0 nF VDC= 50.0 V IRMS= 0.0 A | 1 | \$0.01 | 0805 7 mm ² |

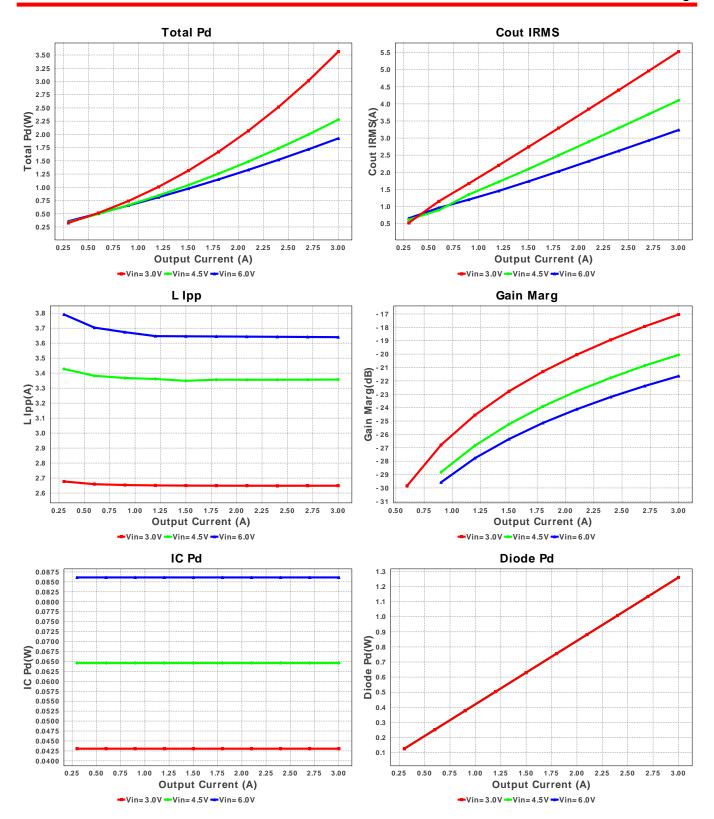
| # Name | Manufacturer | Part Number | Properties | Qty | Price | Footprint |
|------------|---------------------------|------------------------------------|--|-----|--------|----------------------------|
| 7. Cvcc | MuRata | GRM155C80G474KE01D Series= 379 | Cap= 470.0 nF VDC= 4.0 V IRMS= 0.0 A | 1 | \$0.01 | 0402 3 mm ² |
| 8. D1 | Vishay-Semiconductor | SL42-E3/57T | VF@lo= 420.0 mV VRRM= 20.0 V | 1 | \$0.32 | SMC 83 mm ² |
| 9. L1 | Coilcraft | XAL7070-182MEB | L= 1.8 μH DCR= 4.1 mOhm | 1 | \$1.05 | XAL7070 87 mm ² |
| 10. M1 | Texas Instruments | CSD16325Q5 | VdsMax= 25.0 V IdsMax= 100.0 Amps | 1 | \$0.84 | TRANS_NexFET_Q5 55 mm² |
| 11. Rcomp | Vishay-Dale | CRCW04023K16FKED Series= CRCWe3 | Res= 3.16 kOhm Power= 63.0 mW Tolerance= 1.0% | 1 | \$0.01 | 0402 3 mm ² |
| 12. Rfadj | Vishay-Dale | CRCW040240K2FKED Series= CRCWe3 | Res= 40.2 kOhm Power= 63.0 mW Tolerance= 1.0% | 1 | \$0.01 | 0402 3 mm ² |
| 13. Rfb1 | Vishay-Dale | CRCW04021K00FKED Series= CRCWe3 | Res= 1000.0 Ohm Power= 63.0 mW Tolerance= 1.0% | 1 | \$0.01 | 0402 3 mm ² |
| 14. Rfb2 | Vishay-Dale | CRCW04028K45FKED Series= CRCWe3 | Res= 8.45 kOhm Power= 63.0 mW Tolerance= 1.0% | 1 | \$0.01 | 0402 3 mm ² |
| 15. Rivp1 | Vishay-Dale | CRCW040245K3FKED Series= CRCWe3 | Res= 45.3 kOhm Power= 63.0 mW Tolerance= 1.0% | 1 | \$0.01 | 0402 3 mm ² |
| 16. Rivp2 | Vishay-Dale | CRCW040241K2FKED Series= CRCWe3 | Res= 41.2 kOhm Power= 63.0 mW Tolerance= 1.0% | 1 | \$0.01 | 0402 3 mm ² |
| 17. Rs1 | Vishay-Dale | CRCW0402100RFKED Series= CRCWe3 | Res= 100.0 Ohm Power= 63.0 mW Tolerance= 1.0% | 1 | \$0.01 | 0402 3 mm ² |
| 18. Rsense | Stackpole Electronics Inc | CSNL1206FT3L00 Series= 478 | Res= 3.0 mOhm Power= 1.0 W Tolerance= 1.0% | 1 | \$0.19 | 1206 11 mm ² |
| 19. U1 | Texas Instruments | LM3481MM/NOPB | Switcher | 1 | \$0.80 | |
| | | | | | | MUB10A 24 mm ² |

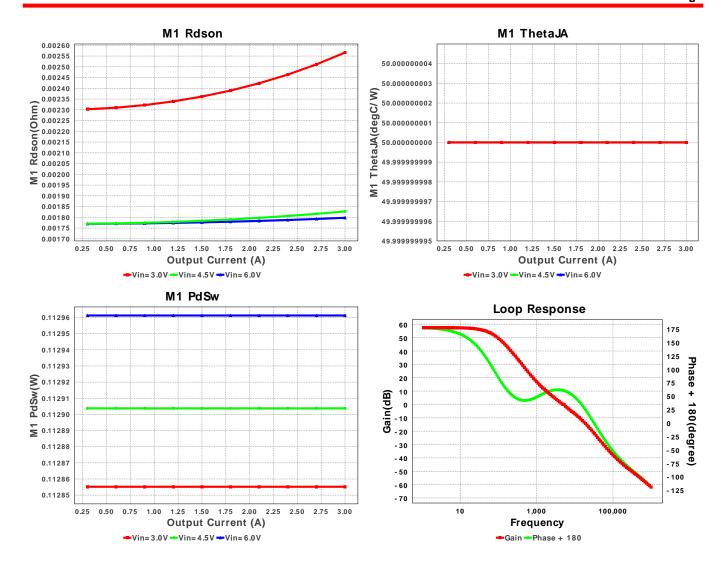












Operating Values

| Ohe | railing values | | | |
|-----|----------------|-----------------------|----------|---|
| # | Name | Value | Category | Description |
| 1. | Cin IRMS | 764.578 mA | Current | Input capacitor RMS ripple current |
| 2. | Cout IRMS | 5.528 A | Current | Output capacitor RMS ripple current |
| 3. | lin Avg | 13.18 A | Current | Average input current |
| 4. | L lpp | 2.649 A | Current | Peak-to-peak inductor ripple current |
| 5. | L1 Irms | 13.165 A | Current | Inductor ripple current |
| 6. | M1 Irms | 15.597 A | Current | M1 MOSFET Irms |
| 7. | SW lpk | 14.467 A | Current | Peak switch current |
| 8. | BOM Count | 20 | General | Total Design BOM count |
| 9. | FootPrint | 626.0 mm ² | General | Total Foot Print Area of BOM components |
| 10. | Frequency | 479.249 kHz | General | Switching frequency |
| 11. | IC Tolerance | 19.0 mV | General | IC Feedback Tolerance |
| 12. | M Vds Act | 39.877 mV | General | M Vds |
| 13. | M1 Rdson | 2.557 mOhm | General | Drain-Source On-resistance |
| 14. | M1 ThetaJA | 50.0 degC/W | General | MOSFET junction-to-ambient thermal resistance |
| 15. | Pout | 36.0 W | General | Total output power |
| 16. | Total BOM | \$5.17 | General | Total BOM Cost |
| 17. | D1 Tj | 93.0 degC | Op_Point | D1 junction temperature |
| 18. | Vout OP | 12.0 V | Op_Point | Operational Output Voltage |
| 19. | Cross Freq | 2.566 kHz | Op_point | Bode plot crossover frequency |
| 20. | Duty Cycle | 77.174 % | Op_point | Duty cycle |
| 21. | Efficiency | 91.045 % | Op_point | Steady state efficiency |
| 22. | Gain Marg | -17.043 dB | Op_point | Bode Plot Gain Margin |
| 23. | IC Tj | 38.628 degC | Op_point | IC junction temperature |
| 24. | ICThetaJA | 200.0 degC/W | Op_point | IC junction-to-ambient thermal resistance |
| 25. | IOUT_OP | 3.0 A | Op_point | lout operating point |
| 26. | M1 TjOP | 65.861 degC | Op_point | M1 MOSFET junction temperature |
| 27. | Phase Marg | 56.206 deg | Op_point | Bode Plot Phase Margin |
| 28. | VIN_OP | 3.0 V | Op_point | Vin operating point |
| 29. | Vout p-p | 115.737 mV | Op_point | Peak-to-peak output ripple voltage |
| 30. | Cin Pd | 8.184 mW | Power | Input capacitor power dissipation |
| 31. | Cout Pd | 244.497 mW | Power | Output capacitor power dissipation |
| | | | | |

| # | Name | Value | Category | Description |
|-----|---------------|------------|----------|-----------------------------------|
| 32. | Diode Pd | 1.26 W | Power | Diode power dissipation |
| 33. | IC Pd | 43.14 mW | Power | IC power dissipation |
| 34. | L Pd | 852.735 mW | Power | Inductor power dissipation |
| 35. | M1 Pd | 717.225 mW | Power | M1 MOSFET total power dissipation |
| 36. | M1 PdCond | 621.951 mW | Power | M1 MOSFET conduction losses |
| 37. | M1 PdSw | 95.274 mW | Power | M1 MOSFET switching losses |
| 38. | Rfb Pd | 15.238 mW | Power | Rfb Power Dissipation |
| 39. | Total Pd | 3.541 W | Power | Total Power Dissipation |
| 40. | Low Freq Gain | 51.113 dB | Unknown | Gain at 10Hz |

Design Inputs

| # | Name | Value | Description |
|----|---------|--------|------------------------|
| 1. | lout | 3.0 | Maximum Output Current |
| 2. | lout1 | 3.0 | Output Current #1 |
| 3. | VinMax | 6.0 | Maximum input voltage |
| 4. | VinMin | 3.0 | Minimum input voltage |
| 5. | Vout | 12.0 | Output Voltage |
| 6. | Vout1 | 12.0 | Output Voltage #1 |
| 7. | base_pn | LM3481 | Base Product Number |
| 8. | source | DC | Input Source Type |
| 9. | Та | 30.0 | Ambient temperature |

Design Assistance

1. LM3481 Product Folder: http://www.ti.com/product/lm3481: contains the data sheet and other resources.

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